

PULSE-WIDTH-MODULATION CONTROL CIRCUITS

AZ7500E

General Description

The AZ7500E is a voltage mode pulse width modulation switching regulator control circuit designed primarily for power supply control.

The AZ7500E consists of a reference voltage circuit, two error amplifiers, an on-chip adjustable oscillator, a dead-time control (DTC) comparator, a pulse-steering control flip-flop, and an output control circuit. The precision of voltage reference (V_{REF}) is improved up to $\pm 1\%$ through trimming and this provides a better output voltage regulation. The AZ7500E provides for push-pull or single-ended output operation, which can be selected through the output control.

AZ7500E is the enhanced version of AZ7500B for it improves REF Pin's reliability comparing with AZ7500B.

The AZ7500E is available in standard packages of DIP-16 and SOIC-16.

Features

- Stable 4.95V Reference Voltage Trimmed to $\pm 1.0\%$ Accuracy
- Uncommitted Output TR for 200mA Sink or Source Current
- Single-End or Push-Pull Operation Selected by Output Control
- Internal Circuitry Prohibits Double Pulse at Either Output
- Complete PWM Control Circuit with Variable Duty Cycle
- On-Chip Oscillator With Master or Slave Operation

Applications

- SMPS
- Back Light Inverter
- Charger



Figure 1. Package Types of AZ7500E

PULSE-WIDTH-MODULATION CONTROL CIRCUITS

AZ7500E

Pin Configuration

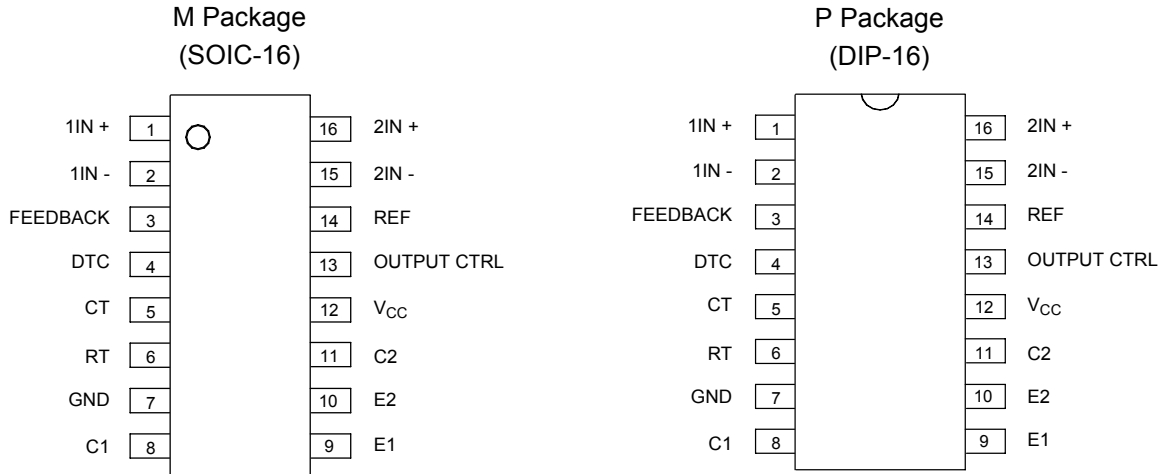


Figure 2. Pin Configuration of AZ7500E (Top View)

Output Function Control Table

| Signal for Output Control | Output Function |
|---------------------------|---------------------------------|
| $V_I = \text{GND}$ | Single-ended or parallel output |
| $V_I = V_{\text{REF}}$ | Normal push-pull operation |

Functional Block Diagram



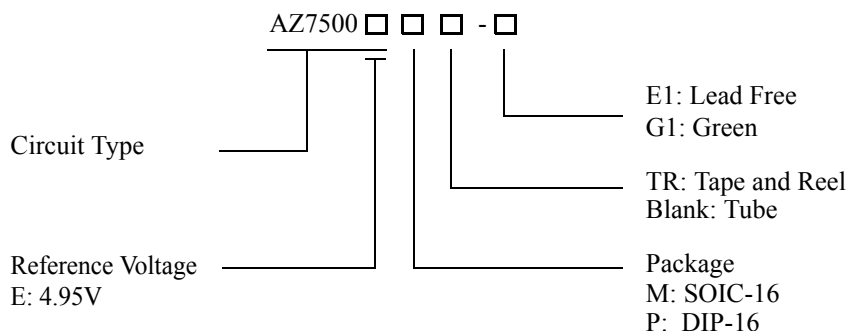
Figure 3. Functional Block Diagram of AZ7500E



PULSE-WIDTH-MODULATION CONTROL CIRCUITS

AZ7500E

Ordering Information



| Package | Temperature Range | Part Number | | Marking ID | | Packing Type |
|---------|-------------------|---------------|---------------|-------------|-------------|--------------|
| | | Lead Free | Green | Lead Free | Green | |
| SOIC-16 | -40 to 85°C | AZ7500EM-E1 | AZ7500EM-G1 | AZ7500EM-E1 | AZ7500EM-G1 | Tube |
| | | AZ7500EMTR-E1 | AZ7500EMTR-G1 | AZ7500EM-E1 | AZ7500EM-G1 | Tape & Reel |
| DIP-16 | | AZ7500EP-E1 | AZ7500EP-G1 | AZ7500EP-E1 | AZ7500EP-G1 | Tube |

BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant. Products with "G1" suffix are available in green packages.

**PULSE-WIDTH-MODULATION CONTROL CIRCUITS****AZ7500E****Absolute Maximum Ratings (Note 1)**

| Parameter | Symbol | Value | Unit |
|---|-----------------|------------------------|------|
| Supply Voltage (Note 2) | V_{CC} | 40 | V |
| Amplifier Input Voltage | V_I | -0.3 to $V_{CC} + 0.3$ | V |
| Collector Output Voltage | V_O | 40 | V |
| Collector Output Current | I_O | 250 | mA |
| Package Thermal Impedance (Note 3) | $R_{\theta JA}$ | M Package | 73 |
| | | P Package | 67 |
| Lead Temperature 1.6mm from case for 10 seconds | | 260 | °C |
| Storage Temperature Range | T_{STG} | -65 to 150 | °C |
| ESD rating (Machine Model) | | 200 | V |

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Note 2: All voltage values are with respect to the network ground terminal.

Note 3: Maximum power dissipation is a function of $T_J(\max)$, $R_{\theta JA}$ and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(\max) - T_A)/R_{\theta JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.

Recommended Operating Conditions

| Parameter | Symbol | Min | Typ | Max | Unit |
|--|------------------|---------|-------|--------------|------|
| Supply Voltage | V_{CC} | 7 | 15 | 36 | V |
| Collector Output Voltage | V_{C1}, V_{C2} | | 30 | 36 | V |
| Collector Output Current (Each Transistor) | I_{C1}, I_{C2} | | | 200 | mA |
| Amplifier Input Voltage | V_I | 0.3 | | $V_{CC} - 2$ | V |
| Current Into Feedback Terminal | I_{FB} | | | 0.3 | mA |
| Reference Output Current | I_{REF} | | | 10 | mA |
| Timing Capacitor | C_T | 0.00047 | 0.001 | 10 | μF |
| Timing Resistor | R_T | 1.8 | 30 | 500 | KΩ |
| Oscillator Frequency | f_{osc} | 1.0 | 40 | 200 | KHz |
| PWM Input Voltage (Pin 3, 4, 14) | | 0.3 | | 5.3 | V |
| Operating Free-Air Temperature | T_A | -40 | | 85 | °C |



PULSE-WIDTH-MODULATION CONTROL CIRCUITS

AZ7500E

Electrical Characteristics

$T_A = 25^{\circ}\text{C}$, $V_{CC}=20\text{V}$, $f=10\text{KHz}$ unless otherwise noted.

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|-----------------------------------|-----------------------|---|------|------|------------|---------------|
| Reference Section | | | | | | |
| Output Reference Voltage | V_{REF} | $I_{REF}=1\text{mA}$ | 4.90 | 4.95 | 5.0 | V |
| | | $I_{REF}=1\text{mA}$, $T_A = -40$ to 85°C | 4.85 | 4.95 | 5.05 | V |
| Line Regulation | R_{LINE} | $V_{CC} = 7\text{V}$ to 36V | | 2 | 25 | mV |
| Load Regulation | R_{LOAD} | $I_{REF}=1\text{mA}$ to 10mA | | 1 | 15 | mV |
| Short-Circuit Output Current | I_{SC} | $V_{REF} = 0\text{V}$ | 10 | 35 | 50 | mA |
| Oscillator Section | | | | | | |
| Oscillator Frequency | f_{OSC} | $C_T=0.001\mu\text{F}$, $R_T=30\text{K}\Omega$ | | 40 | | KHz |
| | | $C_T=0.01\mu\text{F}$, $R_T=12\text{K}\Omega$ | 9.2 | 10 | 10.8 | |
| | | $C_T=0.01\mu\text{F}$, $R_T=12\text{K}\Omega$, $T_A = -40$ to 85°C | 9.0 | | 12 | |
| Frequency Change with Temperature | $\Delta f / \Delta T$ | $C_T=0.01\mu\text{F}$, $R_T=12\text{K}\Omega$, $T_A = -40$ to 85°C | | | 1 | % |
| Dead-Time Control Section | | | | | | |
| Input Bias Current | I_{BIAS} | $V_{CC}=15\text{V}$, $V_4= 0$ to 5.25V | | -2 | -10 | μA |
| Maximum Duty Cycle | $D(\text{MAX})$ | $V_{CC}=15\text{V}$, $V_4= 0\text{V}$, $\text{Pin } 13= V_{REF}$ | 45 | | | % |
| Input Threshold Voltage | V_{ITH} | Zero Duty Cycle | | 3 | 3.3 | V |
| | | Maximum Duty Cycle | 0 | | | |
| Error-Amplifier Section | | | | | | |
| Input Offset Voltage | V_{IO} | $V_3 = 2.5\text{V}$ | | 2 | 10 | mV |
| Input Offset Current | I_{IO} | $V_3 = 2.5\text{V}$ | | 25 | 250 | nA |
| Input Bias Current | I_{BIAS} | $V_3 = 2.5\text{V}$ | | 0.2 | 1 | μA |
| Common-Mode Input Voltage Range | V_{CM} | $V_{CC}=7\text{V}$ to 36V | -0.3 | | $V_{CC}-2$ | V |
| Open-Loop Voltage Gain | G_{VO} | $V_O = 0.5\text{V}$ to 3.5V | 70 | 95 | | dB |
| Unity-Gain Bandwidth | BW | | | 650 | | KHz |
| Common-Mode Rejection Ratio | CMRR | | 65 | 80 | | dB |
| Output Sink Current (Feedback) | I_{SINK} | $V_{ID} = -15\text{mV}$ to -5V , $V_3 = 0.7\text{V}$ | -0.3 | -0.7 | | mA |
| Output Source Current (Feedback) | I_{SOURCE} | $V_{ID}=15\text{mV}$ to 5V $V_3 = 3.5\text{V}$ | 2 | | | mA |



PULSE-WIDTH-MODULATION CONTROL CIRCUITS

AZ7500E

Electrical Characteristics (Continued)

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|---|------------------|---|------|------|------|---------|
| PWM Comparator Section | | | | | | |
| Input Threshold Voltage | V_{ITH} | Zero duty cycle | | 4 | 4.5 | V |
| Input Sink Current | I_{SINK} | $V_3 = 0.7V$ | -0.3 | -0.7 | | mA |
| Output Section | | | | | | |
| Output Saturation Voltage | Common Emitter | $V_{CE(SAT)}$ $V_E = 0V, I_C = 200mA$ | | 1.1 | 1.3 | V |
| | Emitter Follower | $V_{CC(SAT)}$ $V_{CC} = 15V, I_E = -200mA$ | | 1.5 | 2.5 | |
| Collector Off-State Current | $I_C(OFF)$ | $V_{CE} = 36V, V_{CC} = 36V$ | | 2 | 100 | μA |
| Emitter Off-State Current | $I_E(OFF)$ | $V_{CC} = V_C = 36V, V_E = 0$ | | | -100 | μA |
| Total Device | | | | | | |
| Supply Current | I_{CC} | Pin 6 = V_{REF} , $V_{CC} = 15V$ | | 6 | 10 | mA |
| Output Switching Characteristics | | | | | | |
| Rise Time | t_R | Common Emitter Common Collector | | 100 | 200 | ns |
| Fall Time | t_F | Common Emitter Common Collector | | 25 | 100 | ns |

Parameter Measurement information

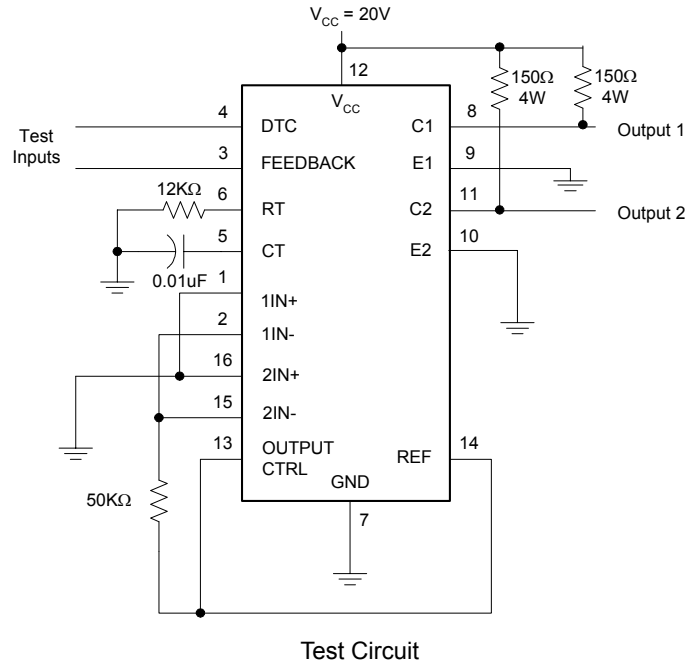


Figure 4. Operational Test Circuit and Waveforms

Parameter Measurement information (Continued)



Figure 5. Error Amplifier Characteristics



Note A: C_L includes probe and jig capacitance.

Figure 6. Common-Emitter Configuration



Note A: C_L includes probe and jig capacitance.

Figure 7. Emitter-Follower Configuration



Typical Performance Characteristics



Figure 8. Oscillator Frequency vs. RT and CT



Figure 9. Error Amplifier Small-Signal Voltage Gain vs. Frequency

Typical Applications

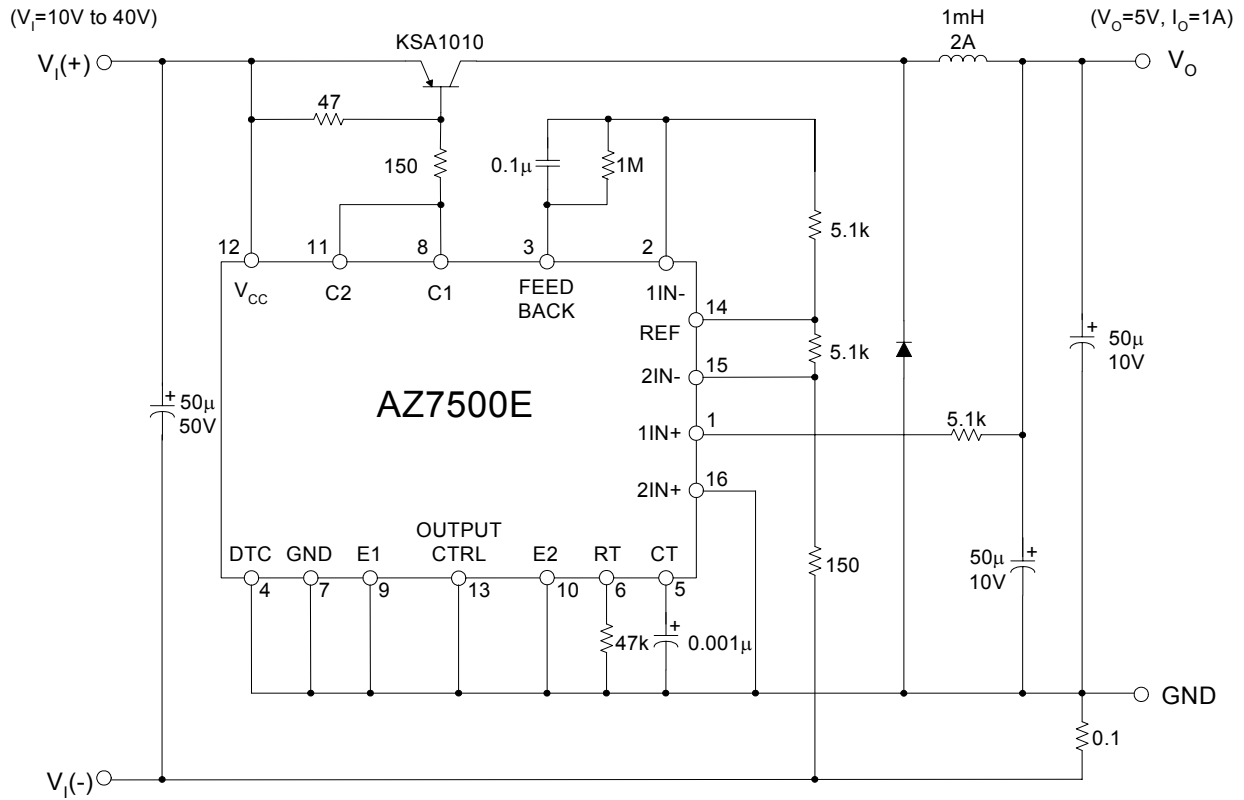
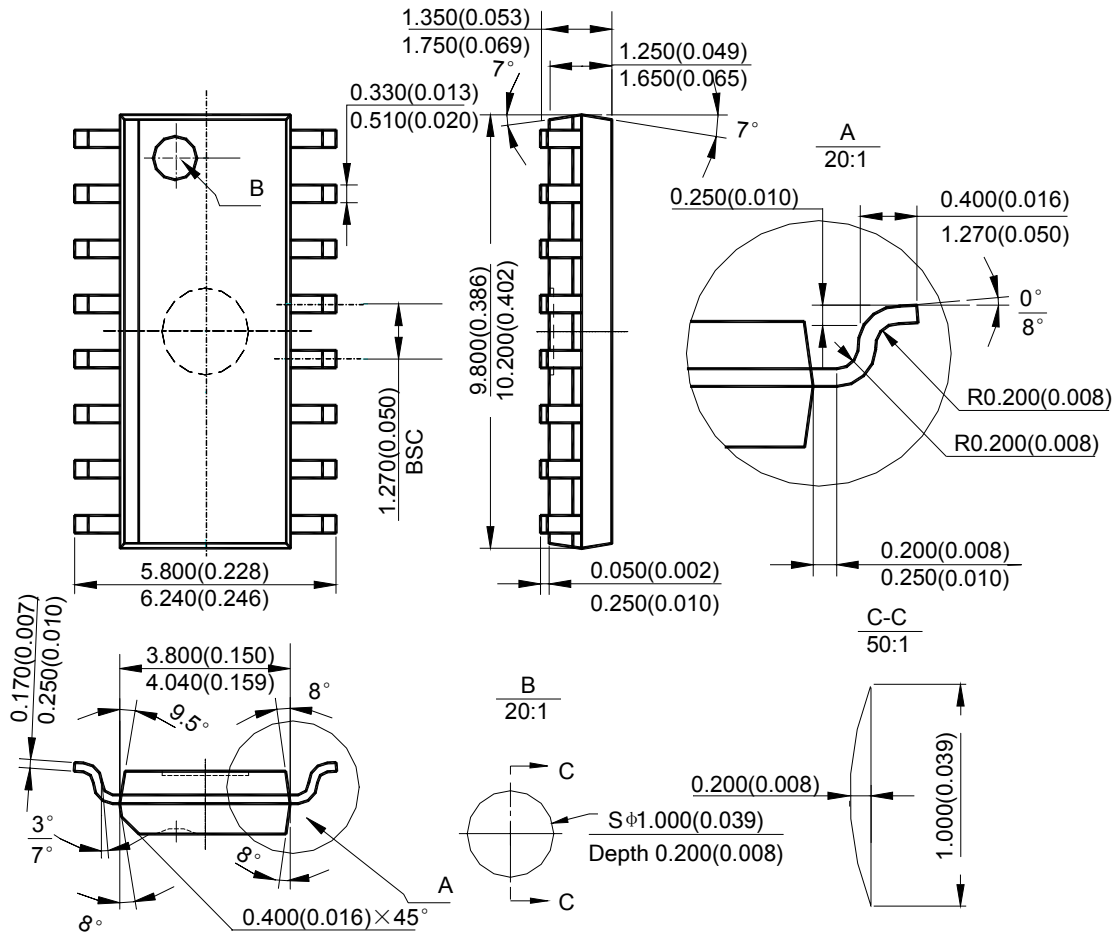


Figure 10. Pulse Width Modulated Step-Down Converter

Mechanical Dimensions

SOIC-16

Unit: mm(inch)



Note: Eject hole, oriented hole and mold mark is optional.



Mechanical Dimensions (Continued)

DIP-16

Unit: mm(inch)



Note: Eject hole, oriented hole and mold mark is optional.



BCD Semiconductor Manufacturing Limited

<http://www.bcdsemi.com>

IMPORTANT NOTICE

BCD Semiconductor Manufacturing Limited reserves the right to make changes without further notice to any products or specifications herein. BCD Semiconductor Manufacturing Limited does not assume any responsibility for use of any its products for any particular purpose, nor does BCD Semiconductor Manufacturing Limited assume any liability arising out of the application or use of any its products or circuits. BCD Semiconductor Manufacturing Limited does not convey any license under its patent rights or other rights nor the rights of others.

MAIN SITE

- Headquarters

BCD Semiconductor Manufacturing Limited

No. 1600, Zi Xing Road, Shanghai Zizhu Science-based Industrial Park, 200241, China
Tel: +86-21-24162266, Fax: +86-21-24162277

- Wafer Fab

Shanghai SIM-BCD Semiconductor Manufacturing Co., Ltd.

800 Yi Shan Road, Shanghai 200233, China
Tel: +86-21-6485 1491, Fax: +86-21-5450 0008

REGIONAL SALES OFFICE

Shenzhen Office

Shanghai SIM-BCD Semiconductor Manufacturing Co., Ltd., Shenzhen Office

Unit A Room 1203, Skyworth Bldg., Gaoxin Ave. 1.S., Nanshan District, Shenzhen, China
Tel: +86-755-8826 7951
Fax: +86-755-8826 7865

Taiwan Office

BCD Semiconductor (Taiwan) Company Limited

4F, 298-1, Rui Guang Road, Nei-Hu District, Taipei, Taiwan
Tel: +886-2-2656 2808
Fax: +886-2-2656 2806

USA Office

BCD Semiconductor Corp.

30920 Huntwood Ave. Hayward, CA 94544, USA
Tel : +1-510-324-2988
Fax: +1-510-324-2788

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкуренспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



Тел: +7 (812) 336 43 04 (многоканальный)

Email: org@lifeelectronics.ru